

Half-Bridge Driver

Features

- Floating channel designed for bootstrap operation
- Fully operational to +600V
- Tolerant to negative transient voltage
- dV/dt immune
- Gate drive supply range from 10 to 20V
- Undervoltage lockout
- 3.3V, 5V and 15V input logic compatible
- Cross-conduction prevention logic
- Internally set dead-time
- High side output in phase with input
- Shut down input turns off both channels
- Matched propagation delay for both channels

Description

The IR25602 is a high voltage, high speed power MOSFET and IGBT driver with dependent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates from 10 to 600 V.

Product Summary

| | |
|------------------|----------------|
| V_{OFFSET} | 600V max. |
| $I_{O+/-}$ | 130 mA/ 270 mA |
| V_{OUT} | 10 – 20V |
| Ton/off (typ.) | 680 & 150 ns |
| Dead time (typ.) | 520 ns |

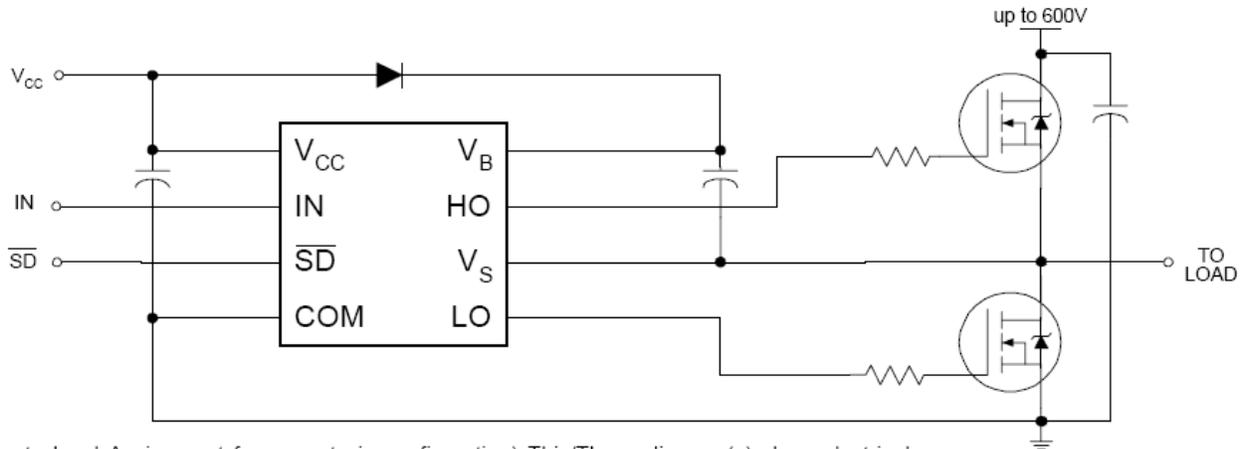
Package Options



Ordering Information

| Base Part Number | Package Type | Standard Pack | | Orderable Part Number |
|------------------|--------------|---------------|----------|-----------------------|
| | | Form | Quantity | |
| IR25602SPBF | SO8N | Tube | 95 | IR25602SPBF |
| IR25602SPBF | SO8N | Tape and Reel | 2500 | IR25602STRPBF |

Typical Connection Diagram



(Refer to Lead Assignment for correct pin configuration) This/These diagram(s) show electrical connections only. Please refer to our Application Notes and DesignTips for proper circuit board layout.

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

| Symbol | Definition | Min. | Max. | Units |
|------------|--|-------------|----------------|--------------------|
| V_B | High side floating absolute voltage | -0.3 | 625 | V |
| V_S | High side floating supply offset voltage | $V_B - 25$ | $V_B + 0.3$ | |
| V_{HO} | High side floating output voltage | $V_S - 0.3$ | $V_B + 0.3$ | |
| V_{CC} | Low side and logic fixed supply voltage | -0.3 | 25 | |
| V_{LO} | Low side output voltage | -0.3 | $V_{CC} + 0.3$ | |
| V_{IN} | Logic input voltage (IN & \overline{SD}) | -0.3 | $V_{CC} + 0.3$ | |
| dVs/dt | Allowable offset supply voltage transient | — | 50 | V/ns |
| P_D | Package power dissipation @ $T_A \leq +25^\circ\text{C}$ | — | 0.625 | W |
| R_{thJA} | Thermal resistance, junction to ambient | — | 200 | $^\circ\text{C/W}$ |
| T_J | Junction temperature | — | 150 | $^\circ\text{C}$ |
| T_S | Storage temperature | -55 | 150 | |
| T_L | Lead temperature (soldering, 10 seconds) | — | 300 | |

Recommended Operating Conditions

For proper operation the device should be used within the recommended conditions. The V_S offset rating is tested with all supplies biased at 15V differential.

| Symbol | Definition | Min. | Max. | Units |
|----------|---|------------|------------|------------------|
| V_B | High side floating supply absolute voltage | $V_S + 10$ | $V_S + 20$ | V |
| V_S | High side floating supply offset voltage | + | 600 | |
| V_{HO} | High side floating output voltage | V_S | V_B | |
| V_{CC} | Low side and logic fixed supply voltage | 10 | 20 | |
| V_{LO} | Low side output voltage | 0 | V_{CC} | |
| V_{IN} | Logic input voltage (IN & \overline{SD}) | 0 | V_{CC} | |
| T_A | Ambient temperature | -40 | 125 | $^\circ\text{C}$ |

+Logic operational for V_S of -5 to +600V. Logic state held for V_S of -5V to - V_{BS} . (Please refer to Design Tip DT97-3 for more details).

Dynamic Electrical Characteristics

V_{BIAS} (V_{CC} , V_{BS}) = 15V, C_L = 1000 pF and T_A = 25°C unless otherwise specified.

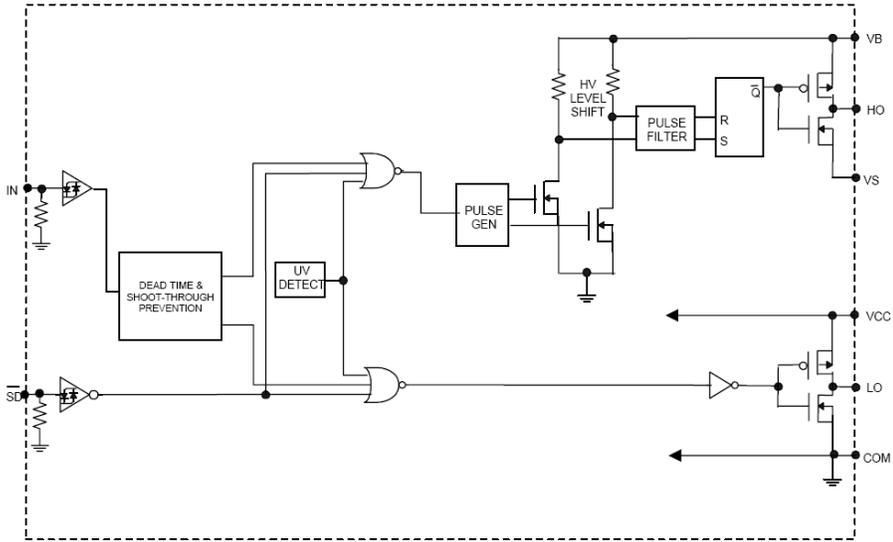
| Symbol | Definition | Min. | Typ. | Max. | Units | Test Conditions |
|-----------|--|------|------|------|-------|-----------------|
| t_{on} | Turn-on propagation delay | — | 680 | 820 | ns | $V_S = 0V$ |
| t_{off} | Turn-off propagation delay | — | 150 | 220 | | $V_S = 600V$ |
| t_{sd} | Shutdown propagation delay | — | 160 | 220 | | |
| t_r | Turn-on rise time | — | 100 | 170 | | |
| t_f | Turn-off fall time | — | 50 | 90 | | |
| DT | Dead time, LS turn-off to HS turn-on & HS turn-on to LS turn-off | 400 | 520 | 650 | | |
| MT | Delay matching, HS & LS turn-on/off | — | — | 60 | | |

Static Electrical Characteristics

V_{BIAS} (V_{CC} , V_{BS}) = 15V and T_A = 25°C unless otherwise specified. The V_{IN} , V_{TH} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

| Symbol | Definition | Min. | Typ. | Max. | Units | Test Conditions |
|--------------|---|------|------|------|---------|-----------------------------------|
| V_{IH} | Logic "1" (HO) & Logic "0" (LO) input voltage | 3 | — | — | V | $V_{CC} = 10V$ to 20V |
| V_{IL} | Logic "0" (HO) & Logic "1" (LO) input voltage | — | — | 0.8 | | $V_{CC} = 10V$ to 20V |
| $V_{SD,TH+}$ | SD input positive going threshold | 3 | — | — | | $V_{CC} = 10V$ to 20V |
| $V_{SD,TH-}$ | SD input negative going threshold | — | — | 0.8 | | $V_{CC} = 10V$ to 20V |
| V_{OH} | High level output voltage, $V_{BIAS} - V_O$ | — | — | 100 | mV | $I_O = 0A$ |
| V_{OL} | Low level output voltage, V_O | — | — | 100 | | $I_O = 0A$ |
| I_{LK} | Offset supply leakage current | — | — | 50 | μA | $V_B = V_S = 600V$ |
| I_{QBS} | Quiescent V_{BS} supply current | — | 30 | 55 | | $V_{IN} = 0V$ or 5V |
| I_{QCC} | Quiescent V_{CC} supply current | — | 150 | 270 | | $V_{IN} = 0V$ or 5V |
| I_{IN+} | Logic "1" input bias current | — | 3 | 10 | | $V_{IN} = 5V$ |
| I_{IN-} | Logic "0" input bias current | — | — | 1 | | $V_{IN} = 0V$ |
| V_{CCUV+} | V_{CC} supply undervoltage positive going threshold | 8 | 8.9 | 9.8 | V | |
| V_{CCUV-} | V_{CC} supply undervoltage negative going threshold | 7.4 | 8.2 | 9 | | |
| I_{O+} | Output high short circuit pulsed current | 130 | 210 | — | mA | $V_O = 0V$ $PW \leq 10 \mu s$ |
| I_{O-} | Output low short circuit pulsed current | 270 | 360 | — | | $V_O = 15V$ $PW \leq 10 \mu s$ |

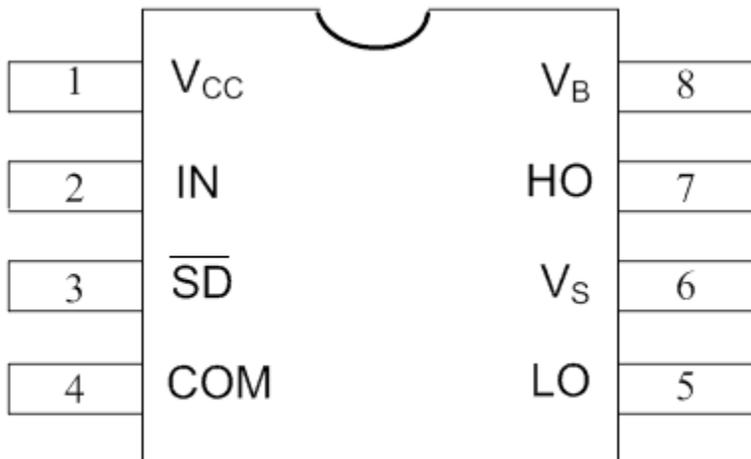
Functional Block Diagram



Lead Definitions

| Symbol | Description |
|-----------------|---|
| IN | Logic input for high and low side gate driver outputs (HO and LO), in phase with HO |
| \overline{SD} | Logic input for shutdown |
| V_B | High side floating supply |
| HO | High side gate drive output |
| V_S | High side floating supply return |
| V_{CC} | Low side and logic fixed supply |
| LO | Low side gate drive output |
| COM | Low side return |

Lead Assignments



Application Information and Additional Details

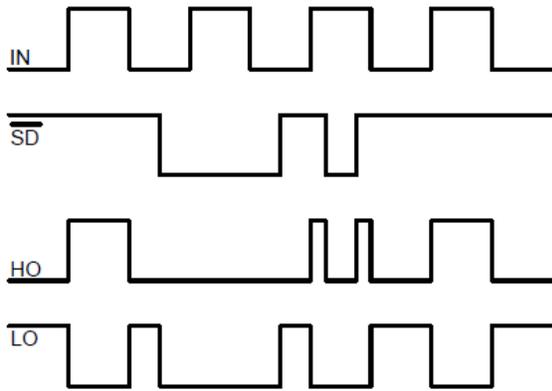


Figure 1. Input/Output Timing Diagram

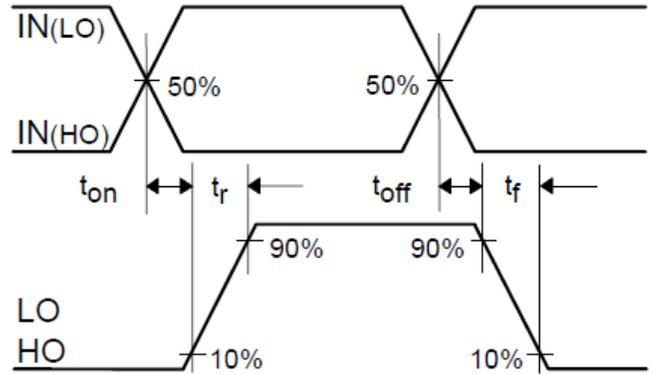


Figure 2. Switching Time Waveform Definitions

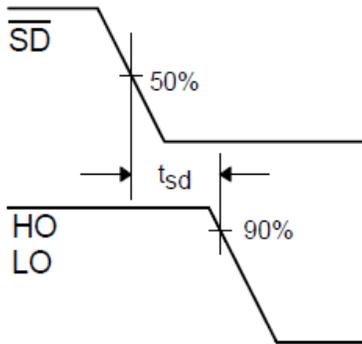


Figure 3. Shutdown Waveform Definitions

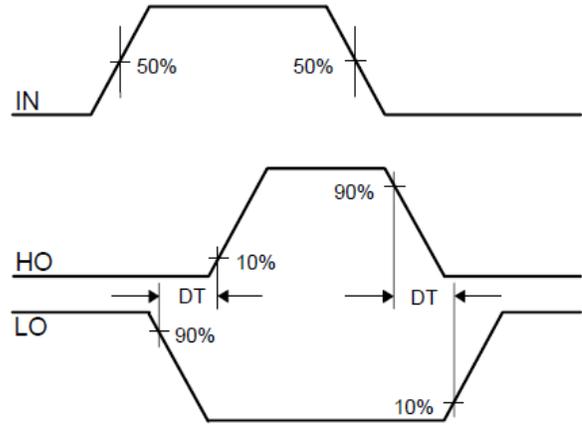


Figure 4. Deadtime Waveform Definitions

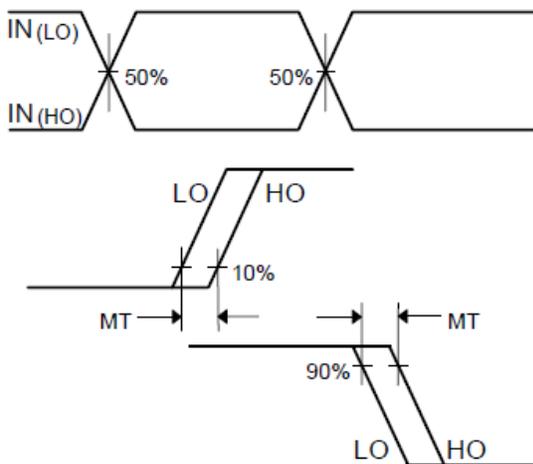


Figure 5. Delay Matching Waveform Definitions

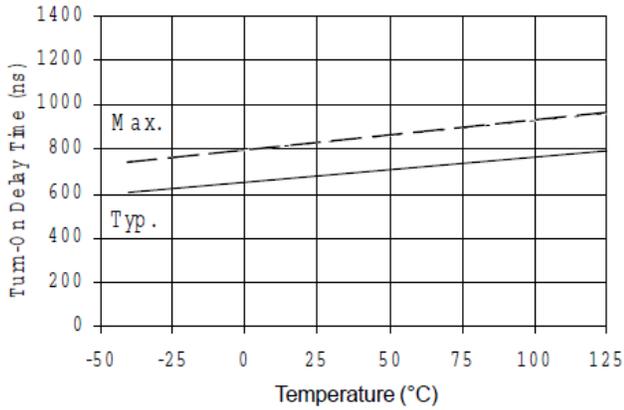


Figure 6A. Turn-On Time vs Temperature

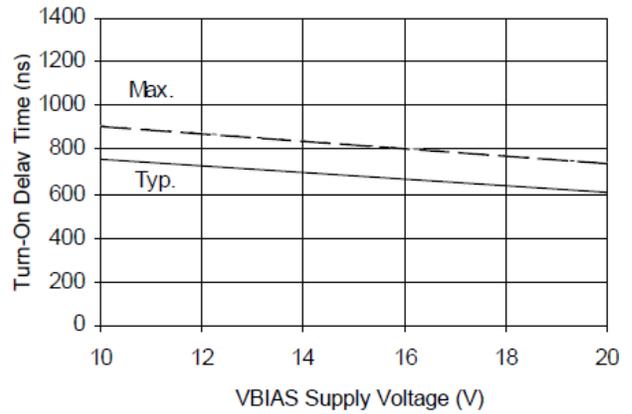


Figure 6B. Turn-On Time vs Supply Voltage

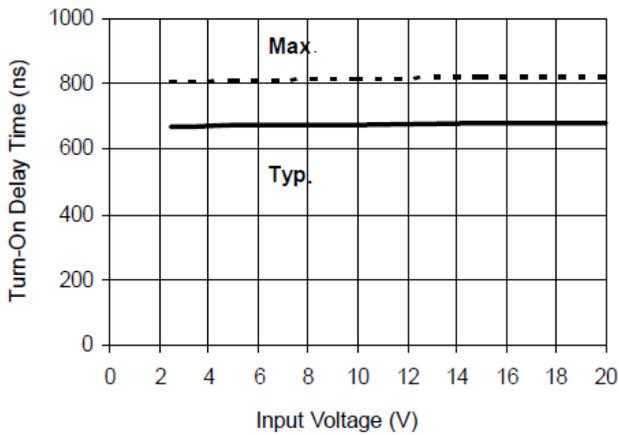


Figure 6C. Turn-On Time vs Input Voltage

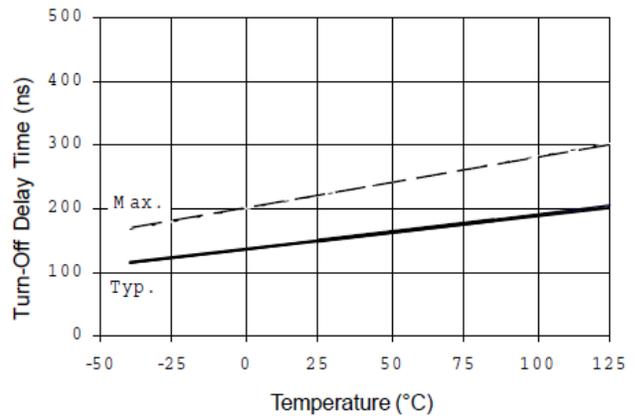


Figure 7A. Turn-Off Time vs Temperature

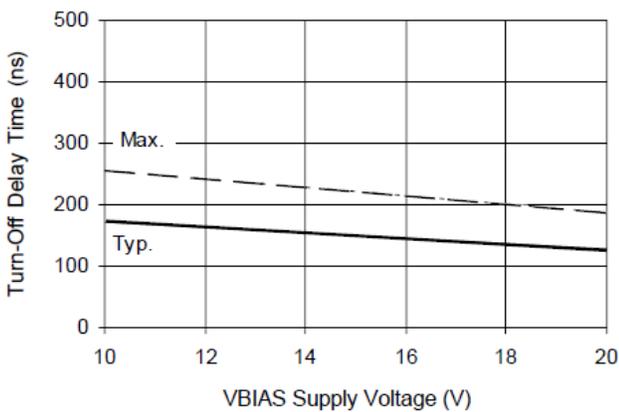


Figure 7B. Turn-Off Time vs Supply Voltage

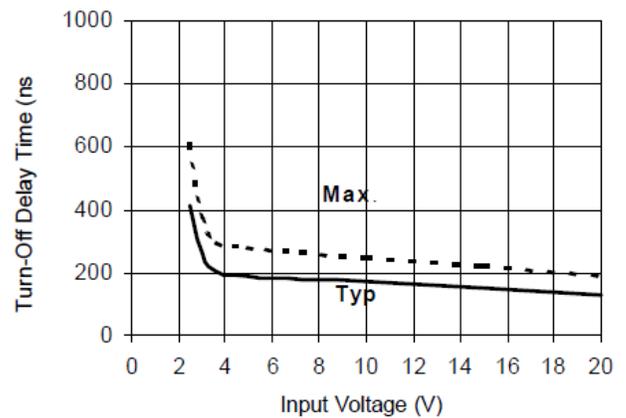


Figure 7C. Turn-Off Time vs Input Voltage

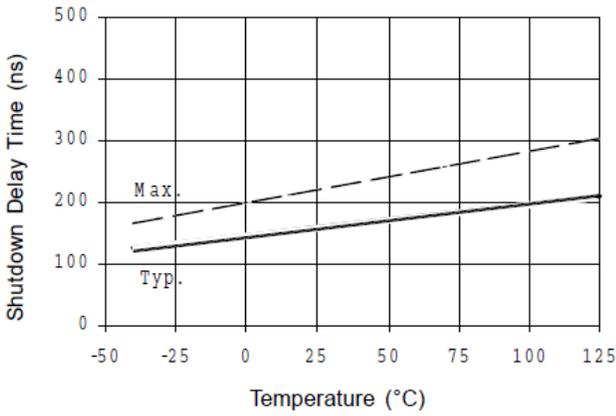


Figure 8A. Shutdown Time vs Temperature

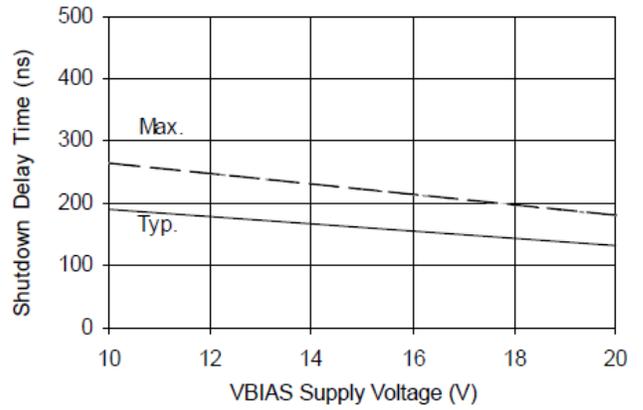


Figure 8B. Shutdown Time vs Voltage

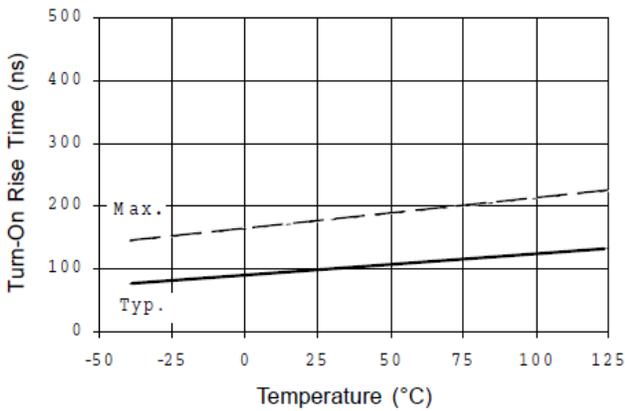


Figure 9A. Turn-On Rise Time vs Temperature

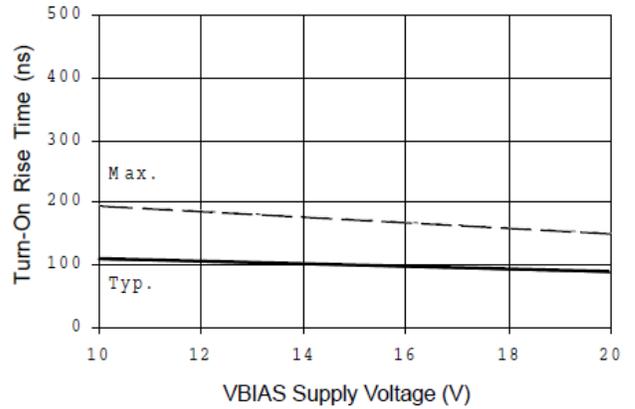


Figure 9B. Turn-On Rise Time vs Voltage

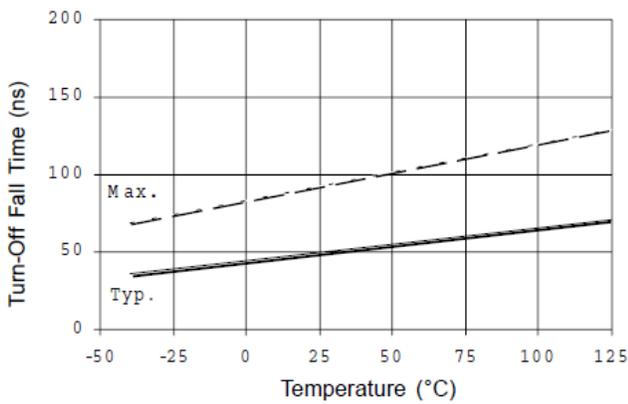


Figure 10A. Turn-Off Fall Time vs Temperature

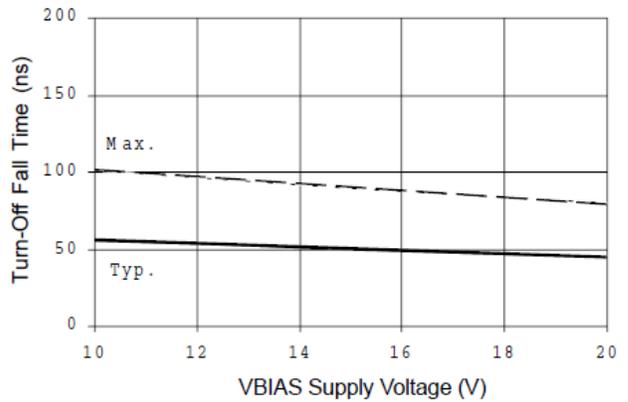


Figure 10B. Turn-Off Fall Time vs Voltage

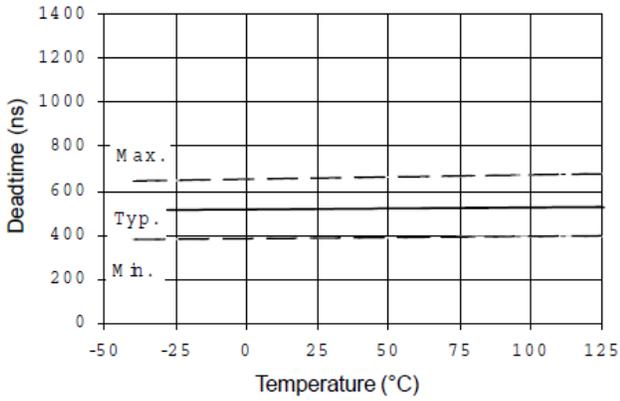


Figure 11A. Deadtime vs Temperature

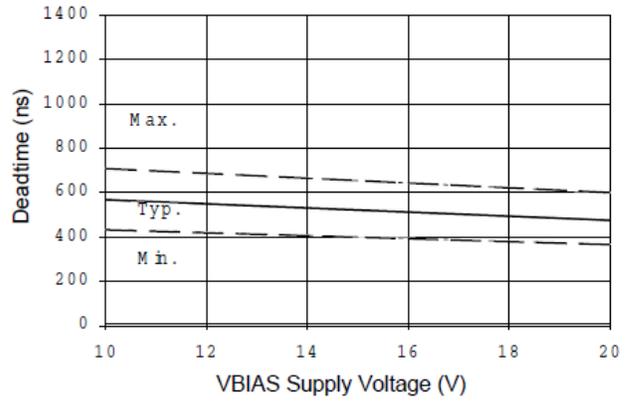


Figure 11B. Deadtime vs Voltage

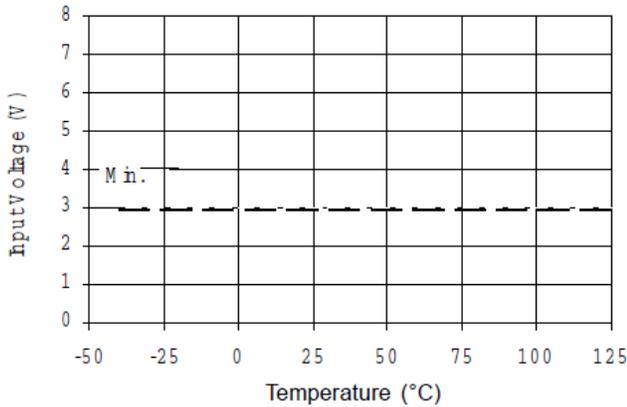


Figure 12A. Logic "1" (HO) & Logic "0" (LO) & Inactive SD Input Voltage vs Temperature

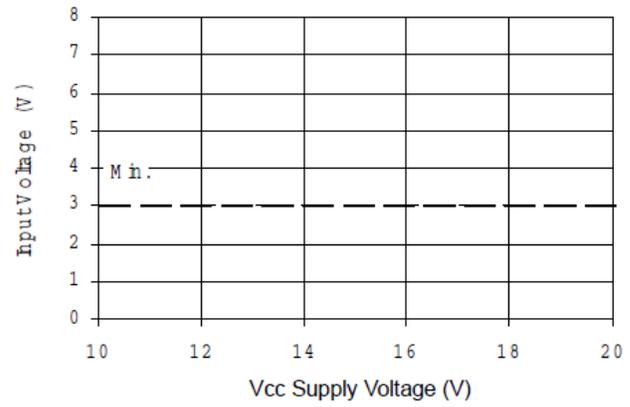


Figure 12B. Logic "1" (HO) & Logic "0" (LO) & Inactive SD Input Voltage vs Voltage

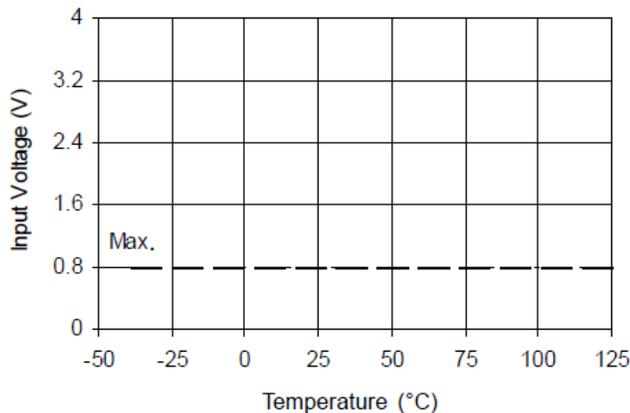


Figure 13A. Logic "0" (HO) & Logic "1" (LO) & Active SD Input Voltage vs Temperature

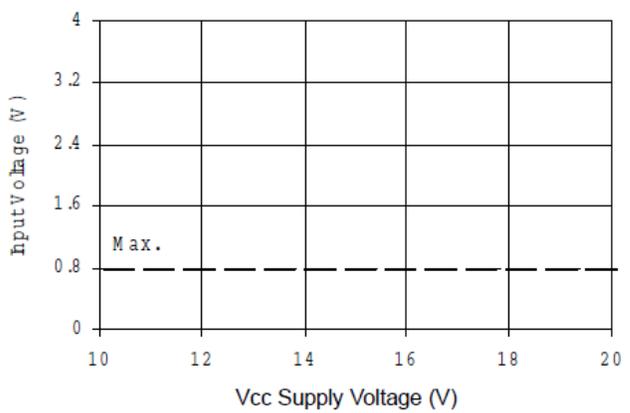


Figure 13B. Logic "0" (HO) & Logic "1" (LO) & Active SD Input Voltage vs Voltage

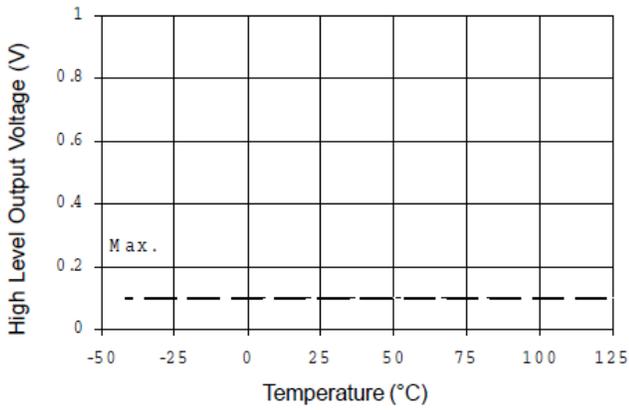


Figure 14A. High Level Output vs Temperature

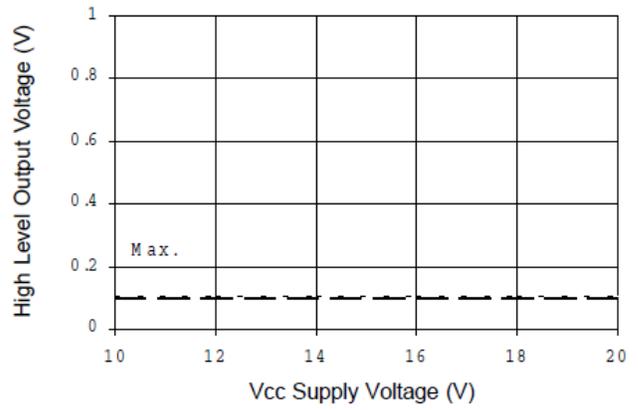


Figure 14B. High Level Output vs Voltage

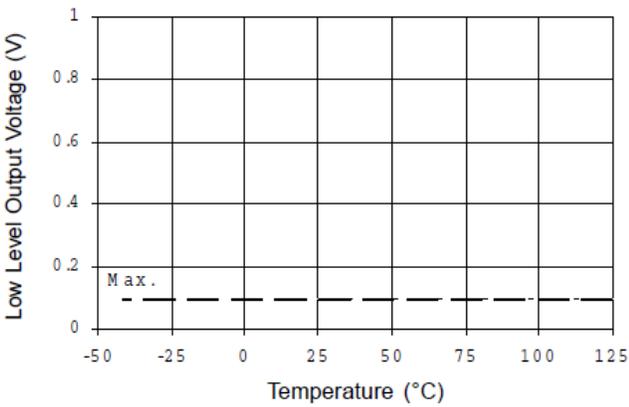


Figure 15A. Low Level Output vs Temperature

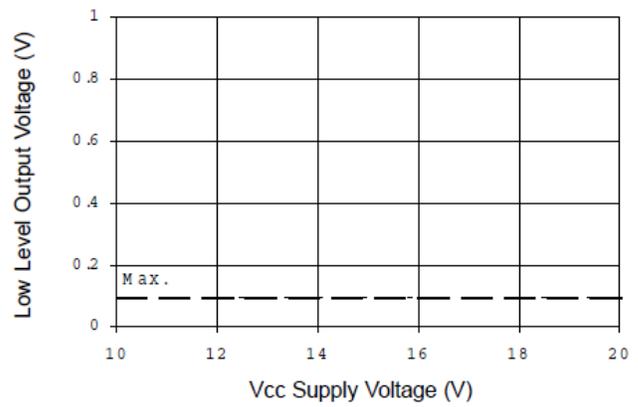


Figure 15B. Low level Output vs Voltage

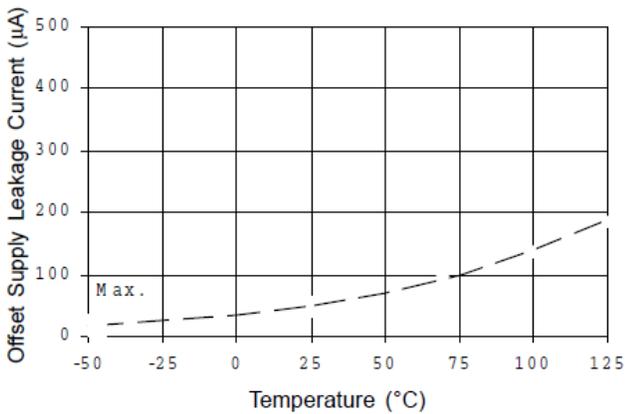


Figure 16A. Offset Supply Current vs Temperature

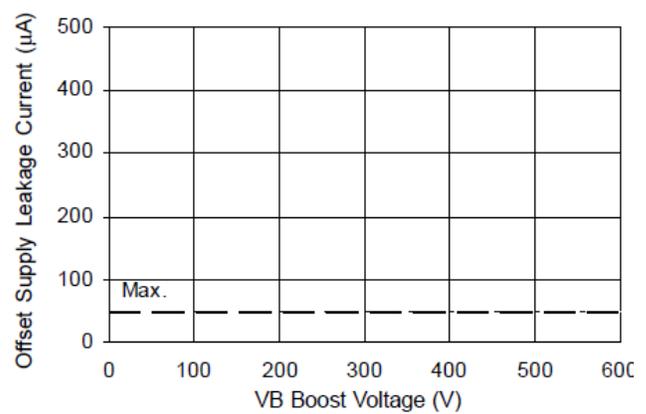


Figure 16B. Offset Supply Current vs Voltage

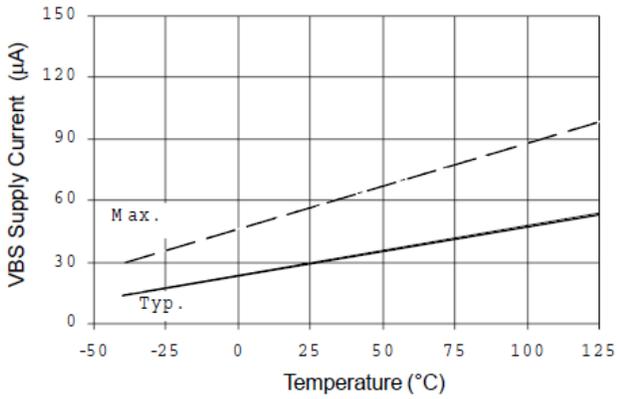


Figure 17A. V_{BS} Supply Current vs Temperature

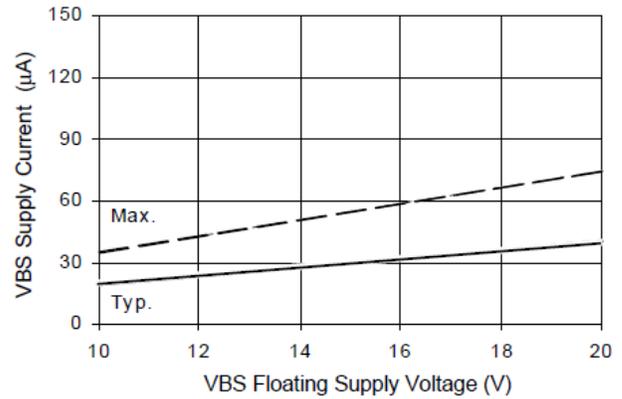


Figure 17B. V_{BS} Supply Current vs Voltage

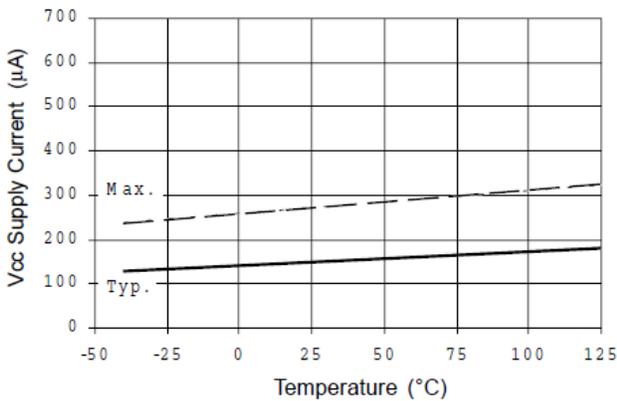


Figure 18A. V_{CC} Supply Current vs Temperature

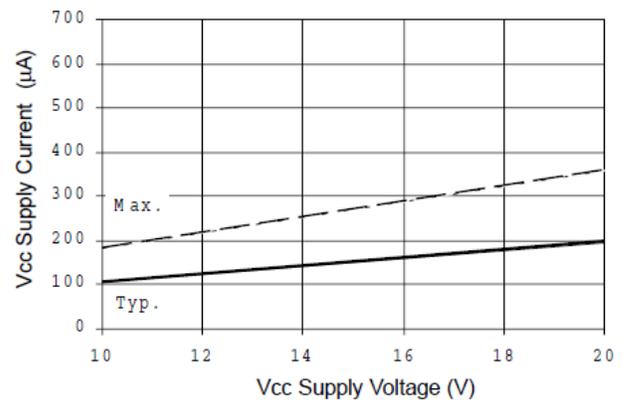


Figure 18B. V_{CC} Supply Current vs Voltage

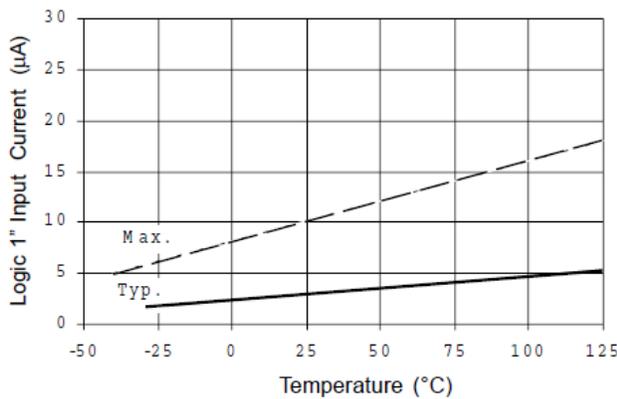


Figure 19A. Logic "1" Input Current vs Temperature

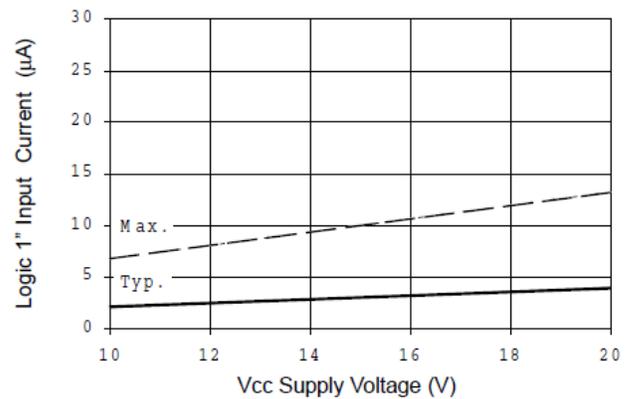


Figure 19B. Logic "1" Input Current vs Voltage

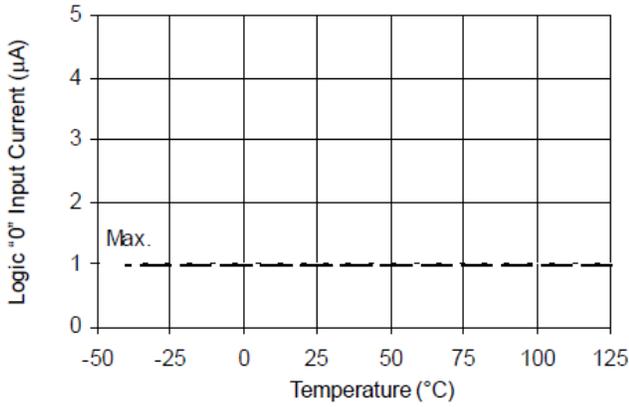


Figure 20A. Logic "0" Input Current vs Temperature

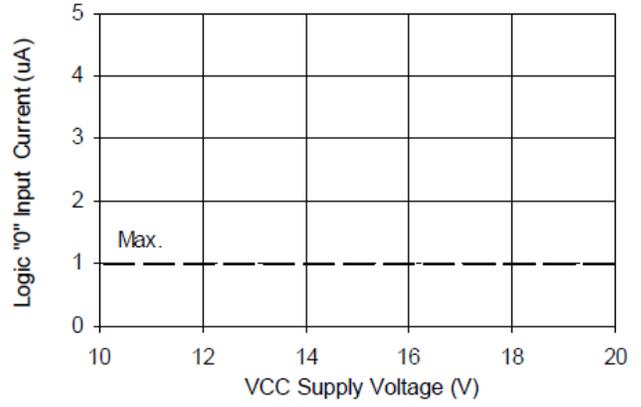


Figure 20B. Logic "0" Input Current vs Voltage

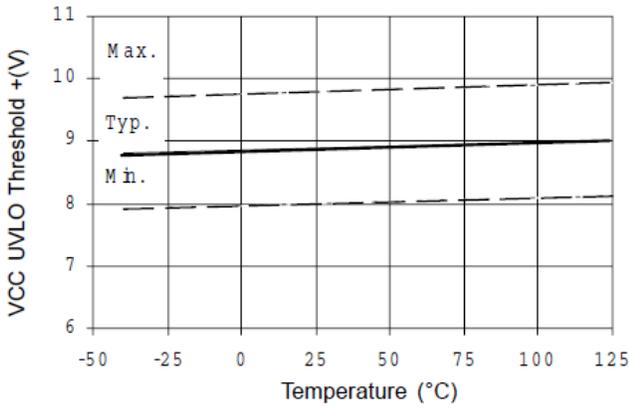


Figure 21A. Vcc Undervoltage Threshold(+) vs Temperature

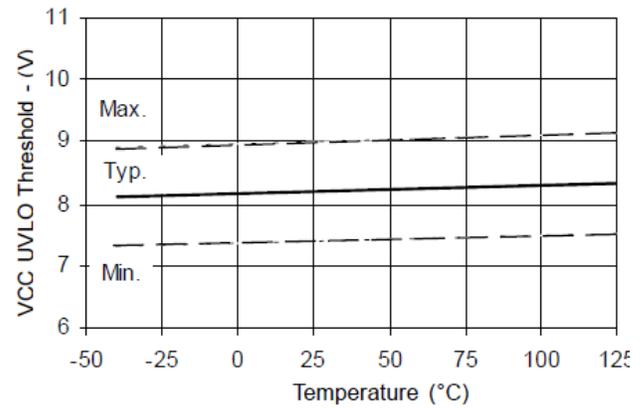


Figure 21B. Vcc Undervoltage Threshold(-) vs Temperature

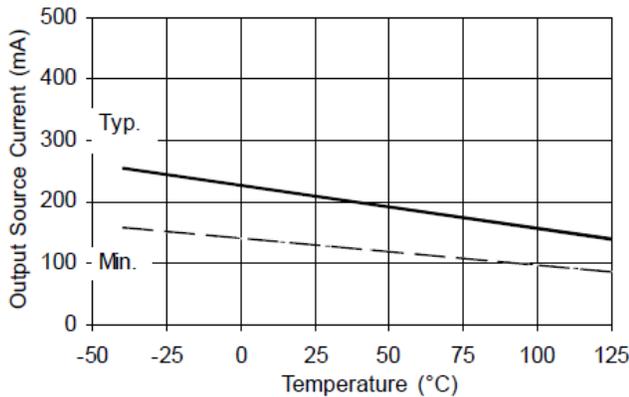


Figure 22A. Output Source Current vs Temperature

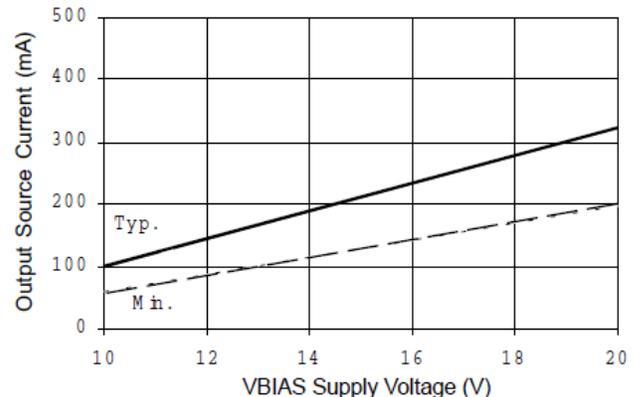


Figure 22B. Output Source Current vs Voltage

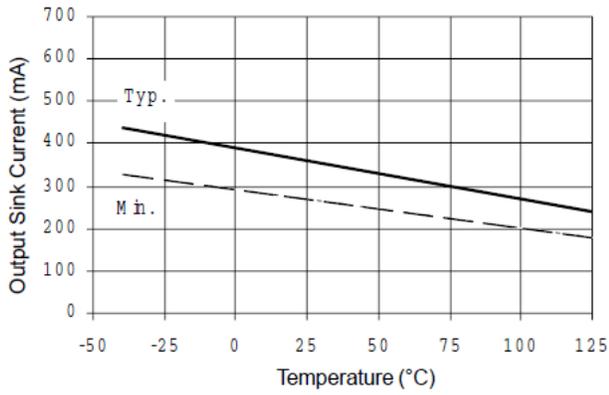


Figure 23A. Output Sink Current vs Temperature

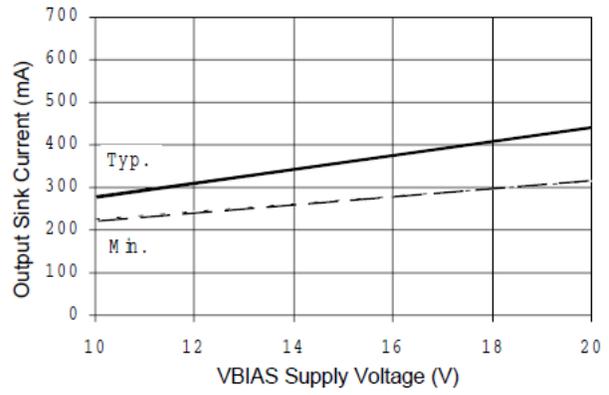
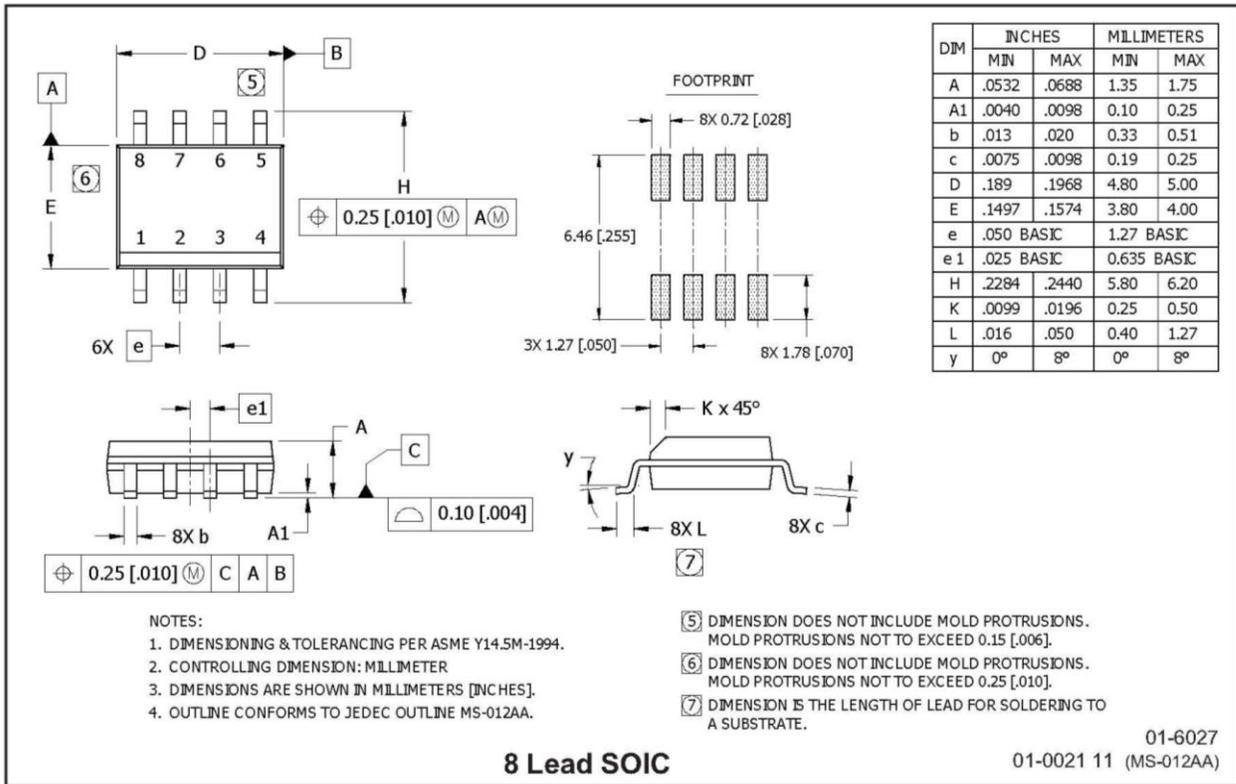
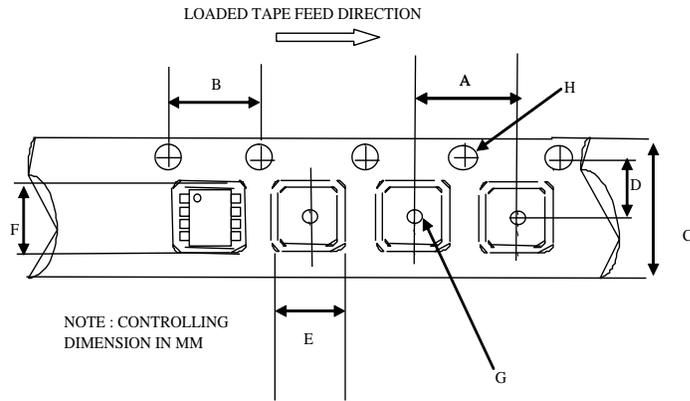


Figure 23B. Output Sink Current vs Voltage

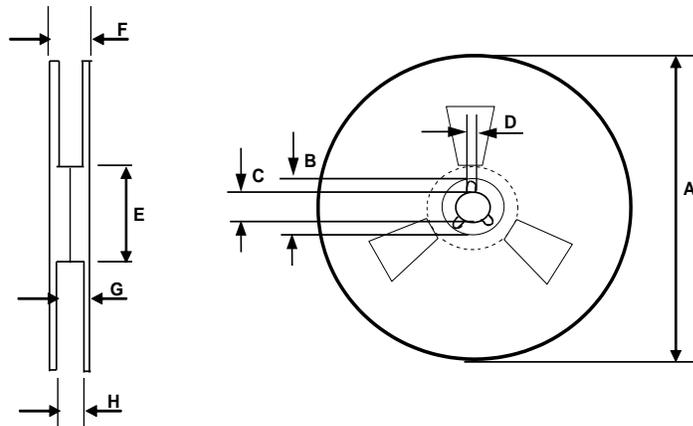
Package Details


Tape and Reel Details



CARRIER TAPE DIMENSION FOR 8SOICN

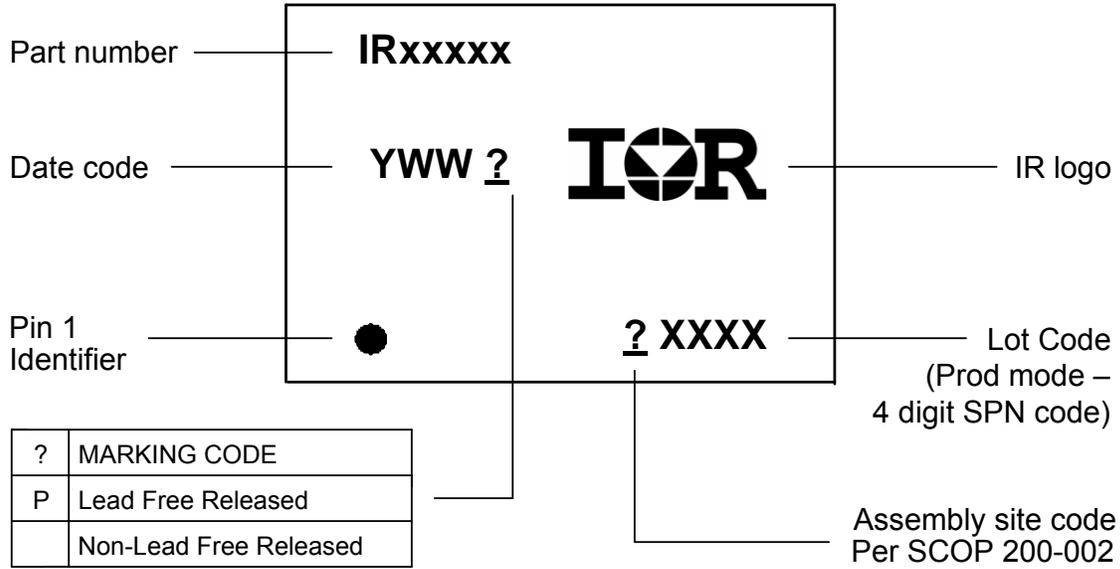
| Code | Metric | | Imperial | |
|------|--------|-------|----------|-------|
| | Min | Max | Min | Max |
| A | 7.90 | 8.10 | 0.311 | 0.318 |
| B | 3.90 | 4.10 | 0.153 | 0.161 |
| C | 11.70 | 12.30 | 0.46 | 0.484 |
| D | 5.45 | 5.55 | 0.214 | 0.218 |
| E | 6.30 | 6.50 | 0.248 | 0.255 |
| F | 5.10 | 5.30 | 0.200 | 0.208 |
| G | 1.50 | n/a | 0.059 | n/a |
| H | 1.50 | 1.60 | 0.059 | 0.062 |



REEL DIMENSIONS FOR 8SOICN

| Code | Metric | | Imperial | |
|------|--------|--------|----------|--------|
| | Min | Max | Min | Max |
| A | 329.60 | 330.25 | 12.976 | 13.001 |
| B | 20.95 | 21.45 | 0.824 | 0.844 |
| C | 12.80 | 13.20 | 0.503 | 0.519 |
| D | 1.95 | 2.45 | 0.767 | 0.096 |
| E | 98.00 | 102.00 | 3.858 | 4.015 |
| F | n/a | 18.40 | n/a | 0.724 |
| G | 14.50 | 17.10 | 0.570 | 0.673 |
| H | 12.40 | 14.40 | 0.488 | 0.566 |

Part Marking Information



Qualification Information[†]

| | |
|-----------------------------------|---|
| Qualification Level | Industrial ^{††} (per JEDEC JESD 47) |
| | Comments: This family of ICs has passed JEDEC's Industrial qualification. IR's Consumer qualification level is granted by extension of the higher Industrial level. |
| Moisture Sensitivity Level | MSL2 ^{†††} (per IPC/JEDEC J-STD-020) |
| RoHS Compliant | Yes |

- † Qualification standards can be found at International Rectifier's web site <http://www.irf.com/>
- †† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.
- ††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.

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